

Amendments to the Claims:

Please cancel claims 2-44

Listing of Claims:

1. (Original) A voltage reading enhancement system for an open digit line array DRAM device comprising a plurality of sub-arrays, the voltage reading enhancement system comprising:

a selective coupling device selectively electrically coupling a component of an active sub-array to a corresponding component of a reference sub-array; and

a controller coupled with the selective coupling device and operable to receive an active row signal, the active row signal indicating an active row of memory cells within the active sub-array is to be coupled with an active digit line, the controller being responsive to the active row signal to direct the selective coupling device to decouple the component in the active sub-array from the corresponding component in the reference sub-array when the active row signal is received.

2-44. (Cancelled)

Amendments to the Drawings:

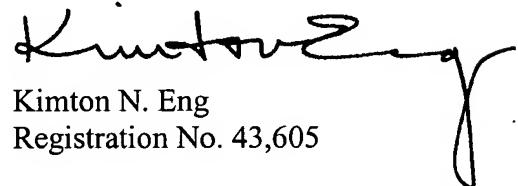
The attached sheets of drawings includes changes to Figures 3A, 3B, and 4.

Also attached are replacement formal drawings, Figures 1-5.

Attachments: Replacement Sheets
Annotated Sheet Showing Changes

Respectfully submitted,

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